

# **isc Silicon NPN Darlington Power Transistor**

2SD962

### **DESCRIPTION**

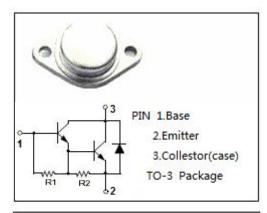
- · High Collector-Emitter Breakdown Voltage-
  - :  $V_{(BR)CEO} = 200V(Min)$
- · High DC Current Gain
- · High Reliability
- Good Linearity of h<sub>FE</sub>
- · Wide Area of Safe Operation
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

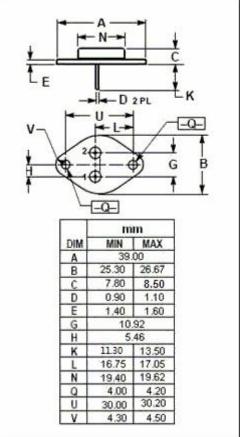


 Designed for series regulators ,color TV, power supplies and similar devices applications.

### ABSOLUTE MAXIMUM RATINGS(T<sub>a</sub>=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
$V_{\text{CBO}}$	Collector-Base Voltage	200	V
Vceo	Collector-Emitter Voltage	200	V
V <sub>EBO</sub>	Emitter-Base Voltage	6	V
Ic	Collector Current-Continuous	5	А
ICP	Collector Current-Peak	8	А
Pc	Collector Power Dissipation @Tc=25°C	80	W
T <sub>j</sub>	Junction Temperature 150		$^{\circ}$
T <sub>stg</sub>	Storage Temperature Range	-55~150	$^{\circ}$







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### **ELECTRICAL CHARACTERISTICS**

 $T_{\text{C}}$ =25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 10mA, I <sub>B</sub> = 0	200			V
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> = 1mA; I <sub>B</sub> = 0	200			V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> = 3mA; I <sub>C</sub> = 0	6			V
V <sub>CE(sat)-1</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 3A ,I <sub>B</sub> = 12mA			2.0	V
V <sub>CE(sat)-2</sub>	Collector-Emitter Saturation voltage	I <sub>C</sub> = 5A ,I <sub>B</sub> = 20mA			4.0	V
V <sub>BE(on)</sub>	Base-Emitter On Voltage	Ic= 3.0A; Vc= 3V			2.5	V
I <sub>CBO</sub>	Collector Cutoff current	V <sub>CB</sub> = 200V, I <sub>E</sub> = 0			0.1	mA
I <sub>CEO</sub>	Collector Cutoff Current	V <sub>CE</sub> = 200V, I <sub>B</sub> = 0			0.5	mA
ІЕВО	Emitter Cutoff Current	V <sub>EB</sub> = 5V; I <sub>C</sub> = 0			3	mA
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = 1A ; V <sub>CE</sub> = 4V	1000		20000	

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